



## **General Description**

The WSP6956 is the highest performance trench Dual N-ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

#### **Features**

- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)

## **Product Summery**

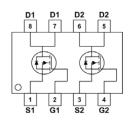
BVDSS	RDSON	ID
60V	15m $\Omega$	10A

## **Applications**

- SMPS Synchronous Rectification.
- DC-DC Conversion.
- Load Switch.

# **SOP-8 Pin Configuration**





# **Absolute Maximum Ratings** (T A = 25°C Unless Otherwise Noted)

Symbol	Parameter	Rating	Unit				
Common	Common Ratings						
V <sub>DSS</sub>	Drain-Source Voltage		60	_ V			
V <sub>GSS</sub>	Gate-Source Voltage		±20	\ \ \ \			
TJ	Maximum Junction Temperature		150	°C			
T <sub>STG</sub>	Storage Temperature Range		-55 to 150	⊢ °C			
Is	Diode Continuous Forward Current	T <sub>A</sub> =25°C	5				
I <sub>D</sub>	Continuous Drain Current	T <sub>A</sub> =25°C	10				
		T <sub>A</sub> =70°C	8	_ A			
I <sub>DM</sub> <sup>a</sup>	Pulsed Drain Current	T <sub>A</sub> =25°C	38				
P <sub>D</sub>	Maximum Dowar Dissination	T <sub>A</sub> =25°C	3.5	W			
	Maximum Power Dissipation	T <sub>A</sub> =70°C	2.2	vv			
P <sub>0JA</sub> c	Thermal Resistance-Junction to Ambient	t ≤ 10s	35	°C ///			
		Steady State	70	- °C/W			
I <sub>AS</sub> b	Avalanche Current, Single pulse	L=0.1mH	27	Α			
E <sub>AS</sub> b	Avalanche Energy, Single pulse	L=0.1mH	36	mJ			

Note a : Pulse width limited by max. junction temperature.

Note b: UIS tested and pulse width limited by maximum junction temperature 150°C (initial temperature Tj=25°C).

Note c: Surface Mounted on 1in<sup>2</sup> pad area.



# **Electrical Characteristics** (T $_{A}$ = 25°C unless otherwise noted)

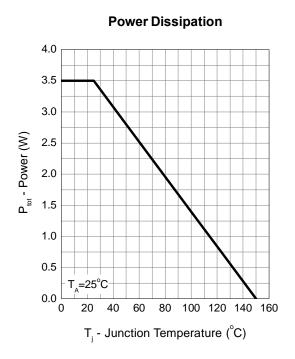
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
Static Cha	Static Characteristics						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>DS</sub> =250μA	60		-	V	
	Zara Cata Valtaga Prain Current	V <sub>DS</sub> =48V, V <sub>GS</sub> =0V	-	-	1	μА	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	T <sub>J</sub> =85°C	-	-	30		
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_{DS}=250\mu A$	1	1.5	2.5	V	
I <sub>GSS</sub>	Gate Leakage Current	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	±100	nA	
<b>D</b> 4	Duaire Courses On state Registeres	V <sub>GS</sub> =10V, I <sub>DS</sub> =10A	-	15	20	mO	
P <sub>DS(ON)</sub> d	Drain-Source On-state Resistance	V <sub>GS</sub> =4.5V, I <sub>DS</sub> =9A		18	24	mΩ	
Diode Cha	aracteristics						
\/ d	Diode Forward Voltage	I <sub>SD</sub> =10A, V <sub>GS</sub> =0V	-	0.8	1.3	V	
trr	Reverse Recovery Time	1 404 11 /11 4004/	-	21	-	ns	
$Q_{rr}$	Reverse Recovery Charge	$I_{SD}$ =10A, $dI_{SD}/dt$ =100A/ $\mu$ S	-	22	-	nC	
Dynamic (	Characteristics <sup>e</sup>						
$R_{G}$	Gate Resistance	V <sub>GS</sub> =0V,V <sub>DS</sub> =0V,f=1MHz	_	2.5	-	Ω	
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V,	-	1370	1780		
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> =30V,	-	135	-	pF	
$C_{rss}$	Reverse Transfer Capacitance	Frequency=1.0MHz	-	60	-		
t <sub>d(ON)</sub>	Turn-on Delay Time	V -20V D -200	-	14	26		
t <sub>r</sub>	Turn-on Rise Time	$V_{DD}$ =30V, $R_L$ =30 $\Omega$ , $I_{DS}$ =1A, $V_{GEN}$ =10V,	-	8	15	ns	
t <sub>d(OFF)</sub>	Turn-off Delay Time	$R_G=6\Omega$	-	38	69		
t <sub>f</sub>	Turn-off Fall Time		-	12	22		
Gate Charge Characteristics <sup>e</sup>							
$Q_g$	Total Gate Charge	V <sub>DS</sub> =30V, V <sub>GS</sub> =4.5V, I <sub>DS</sub> =10A	-	12	-		
$Q_g$	Total Gate Charge	.,	-	26	37	nC	
$Q_{gs}$	Gate-Source Charge	$V_{DS}$ =30V, $V_{GS}$ =10V, $I_{DS}$ =10A	-	5	-		
$Q_{gd}$	Gate-Drain Charge	- 10/1	-	5	-		

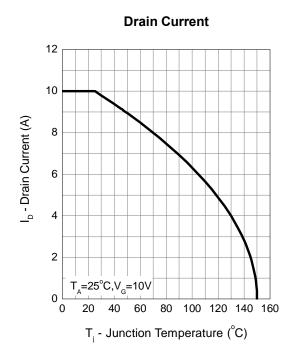
Note d : Pulse test ; pulse width  $\!\leq\!300\mu s,$  duty cycle  $\!\leq\!2\%.$ 

Note e: Guaranteed by design, not subject to production testing.

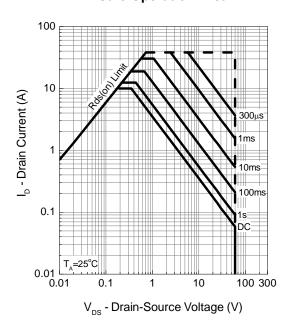


# **Typical Operating Characteristics**

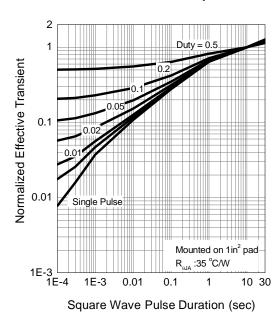




# Safe Operation Area



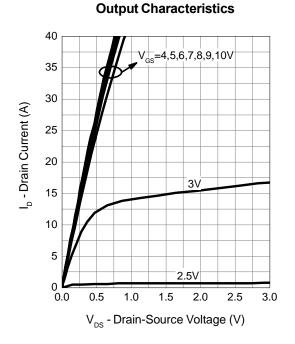
### **Thermal Transient Impedance**



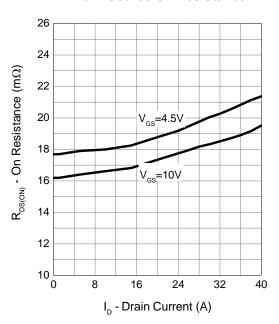


# **Typical Operating Characteristics (Cont.)**

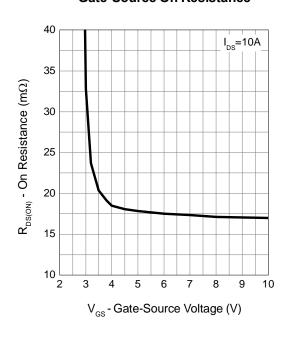




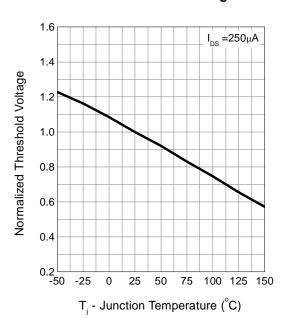
#### **Drain-Source On Resistance**



## **Gate-Source On Resistance**



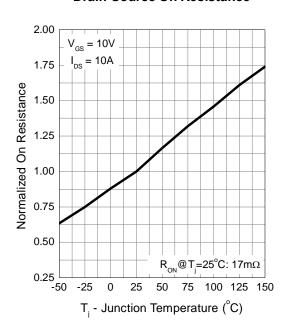
## **Gate Threshold Voltage**



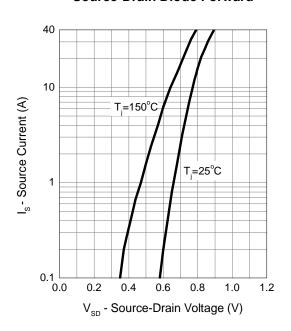


# **Typical Operating Characteristics (Cont.)**

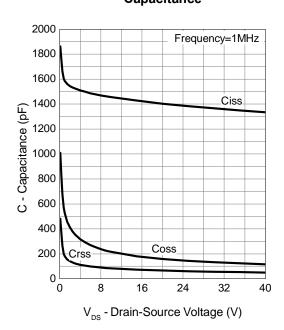
#### **Drain-Source On Resistance**



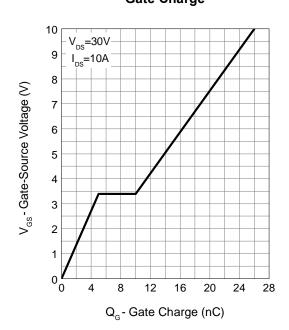
### **Source-Drain Diode Forward**



Capacitance



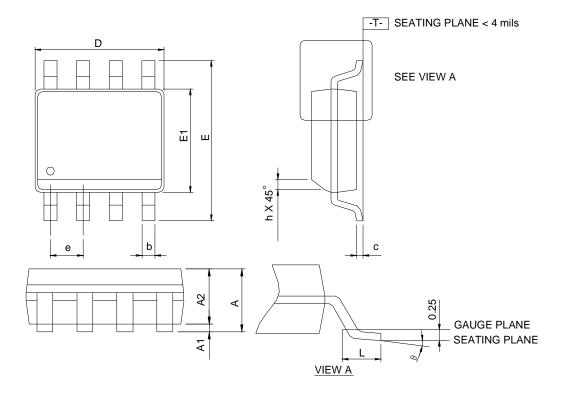
**Gate Charge** 





# **Package Information**

## SOP-8

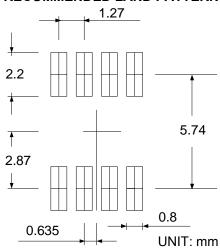


Ş	SOP-8			
SYMBO BO	MILLIMETERS		INCHES	
5	MIN.	MAX.	MIN.	MAX.
Α	-	1.75	-	0.069
A1	0.10	0.25	0.004	0.010
A2	1.25	-	0.049	-
b	0.31	0.51	0.012	0.020
С	0.17	0.25	0.007	0.010
D	4.80	5.00	0.189	0.197
Е	5.80	6.20	0.228	0.244
E1	3.80	4.00	0.150	0.157
е	1.27 BSC		0.050 BSC	
h	0.25	0.50	0.010	0.020
L	0.40	1.27	0.016	0.050
θ	0°	8°	0°	8°

Note: 1. Follow JEDEC MS-012 AA.

- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- Dimension <sup>4</sup>E" does not include inter-lead flash or protrusions. Inter-lead flash and protrusions shall not exceed 10 mil per side.

### **RECOMMENDED LAND PATTERN**





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